

#### **Description**

The AO3404 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

# D G SOT23-3L

#### **General Features**

 $V_{DS} = 30V I_D = 5A$ 

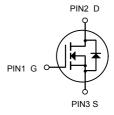
 $R_{DS(ON)}$  < 28m $\Omega$ @ V<sub>GS</sub>=10V

## **Application**

**Battery protection** 

Load switch

Uninterruptible power supply



N-Channel MOSFET

## **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
AO3404	SOT23-3L	X4HV	3000

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

symbol	parameter	limit	unit
V <sub>DS</sub>	Drain-source voltage	30	V
V <sub>GS</sub>	Gate-source voltage	±20	V
ID	Drain current-continuousª@Tj=125℃	5	А
IDM	-pulse <b>d</b> <sup>b</sup>	20	А
ls	Drain-source Diode forward current	5	А
P <sub>D</sub>	Maximum power dissipation	1.4	W
Tj	Operating junction Temperature range	-55—150	°C
Rth JA	Thermal Resistance junction-to ambient	100	°C/W



# **Electrical Characteristics** (TA=25°C unless otherwise noted)

250μA 30 <sub>GS</sub> =0V - <sub>S</sub> =±20V -	-	-	V
	-	1	
s=±20V -			μA
	-	±100	nA
=250µA 0.8	1.4	2.2	V
=5A -	24	28	_
o=4A	26	32	mΩ
5A -	33	-	S
GS=0V	255		pF
	45		
	35		
-	4.5	-	
- ss=10V	2.5	-	_
-	14.5	-	ns
-	3.5	-	-
-	5.2	-	
=5.8A -	0.85	-	nC
-	1.3	-	-
1A -	0.76	1.16	V
	5A - 5S=0V	26 5A - 33 GS=0V 255 45 - 4.5 - 2.5 - 14.5 - 3.5 - 5.2 - 5.2 - 1.3	26 32 5A - 33 -  255 45 35 - 4.5 -  - 2.5 -  - 14.5 -  - 3.5 -  - 5.2 -  - 1.3 -

## Notes:

- 1、surface mounted on FR4 board,t≤10sec
- 2、pulse test: pulse width≤300µs,duty≤2%
- 3, guaranteed by design, not subject to production testing



## **Typical Performance Characteristics**

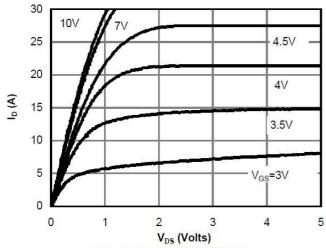


Fig 1: On-Region Characteristics

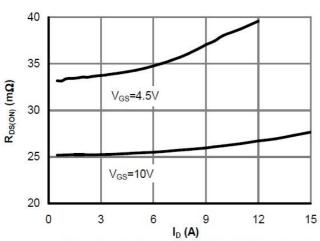


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

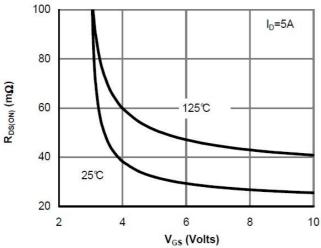


Figure 5: On-Resistance vs. Gate-Source Voltage

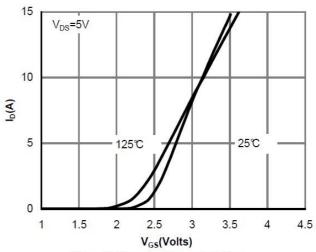


Figure 2: Transfer Characteristics

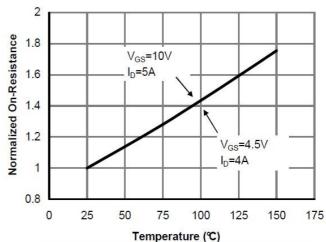


Figure 4: On-Resistance vs. Junction Temperature

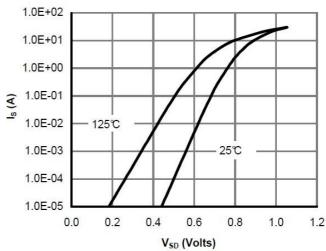
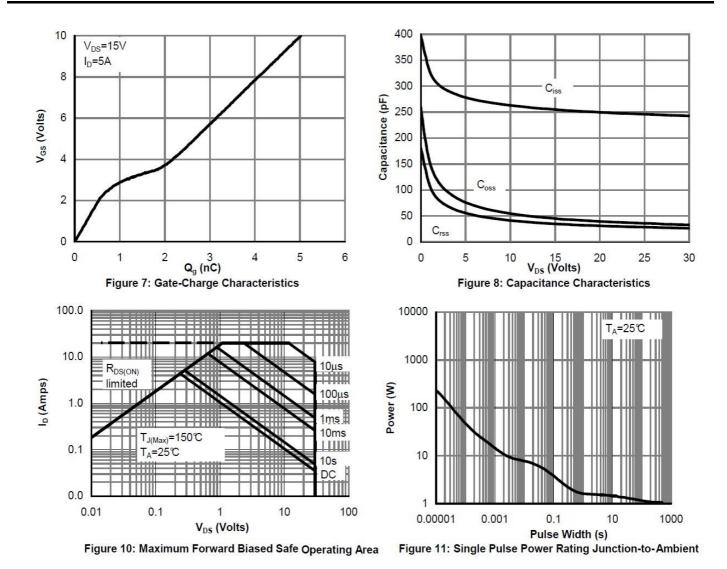
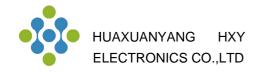


Figure 6: Body-Diode Characteristics

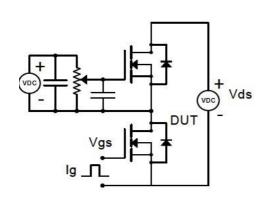


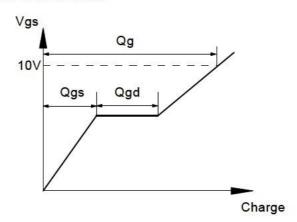
10 D=Ton/T In descending order Z<sub>6JA</sub> Normalized Transient D=0.5, 0.3, 0.1, 0.05, 0.02, 0.01, single pulse  $T_{J,PK}=T_A+P_{DM}.Z_{\theta JA}.R_{\theta JA}$ Thermal Resistance R<sub>θJA</sub>=125℃/W 0.1 0.01 Single Pulse Ton 0.001 0.001 0.01 0.00001 0.0001 0.1 10 100 1000 Pulse Width (s)

Figure 12: Normalized Maximum Transient Thermal Impedance



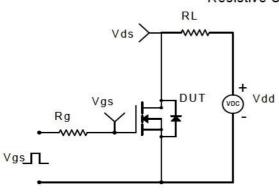
## Gate Charge Test Circuit & Waveform

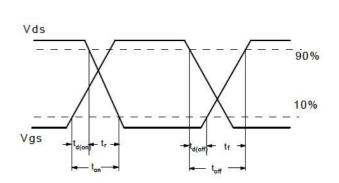




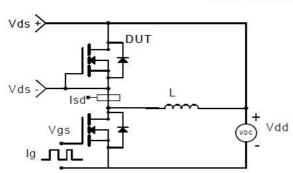
## Resistive Switching Test Circuit & Waveforms

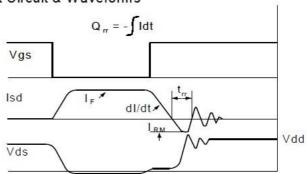
## Resistive Switching Test Circuit & Waveforms





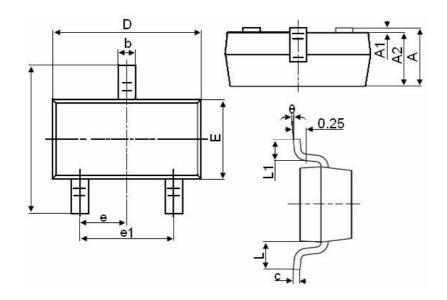
## Diode Recovery Test Circuit & Waveforms







## **SOT23-3L Package Information**



Symbol	Dimensions in Millimeters		
	MIN.	MAX.	
А	1.050	1.250	
A1	0.000	0.100	
A2	1.050	1.150	
b	0.300	0.500	
С	0.100	0.200	
D	2.800	3.000	
E	1.500	1.700	
E1	2.650	2.950	
е	0.950TYP		
e1	1.800	2.000	
L	0.550REF		
L1	0.300	0.600	
θ	0°	8°	



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